

## 2-Line Uni-directional TVS Diode Array

### Features

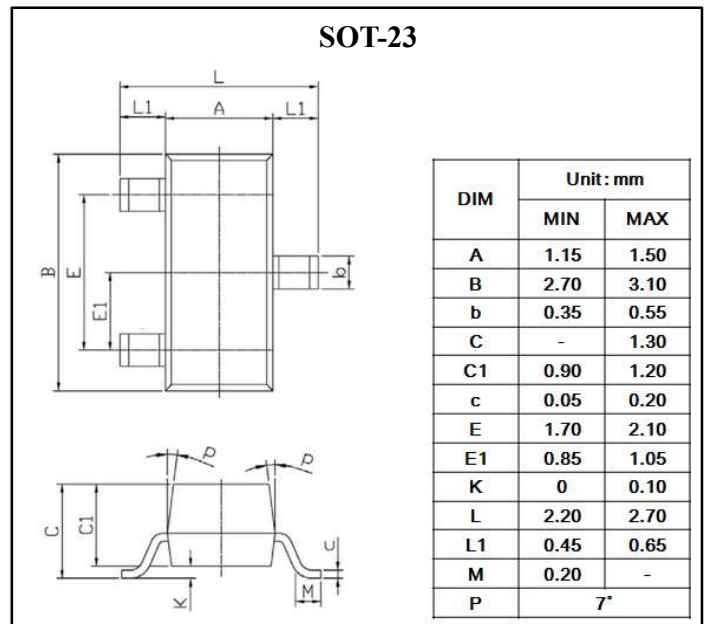
- 240W peak pulse power (8/20us)
- Protects one bi-directional or two uni-directional lines
- Ultra low leakage : nA level
- Operating voltage : 3.3V
- Low clamping voltage
- Complies with following standards :
  - IEC 61000-4-2(ESD) immunity test  
Air discharge :  $\pm 17$ kV, Contact discharge :  $\pm 20$ kV
  - IEC61000-4-4 (EFT) 40A (5/50ns)
  - IEC61000-4-5 (Lightning) 16A (8/20us)
- RoHS Compliant

### Mechanical Data

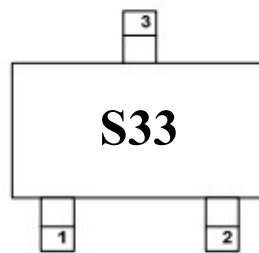
- Package : SOT-23
- Case Material : "Green" Molding Compound.
- Lead Finish : Matte Tin
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity : Level 3 per J-STD-020
- Terminal Connections : See Diagram Below
- Marking Information : See Below

### Applications

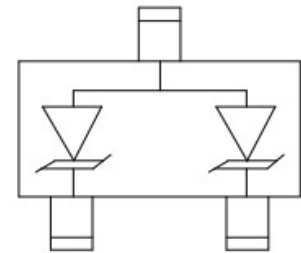
- Cellular Handsets and Accessories
- Notebooks and Handhelds
- Portable Instrumentation
- Set Top Box
- Industrial Controls
- Desktop PC and Servers



### Marking



S33 = Device Marking Code



Circuit and Pin Schematic

### Absolute Maximum Ratings (Ta= 25°C unless otherwise specified)

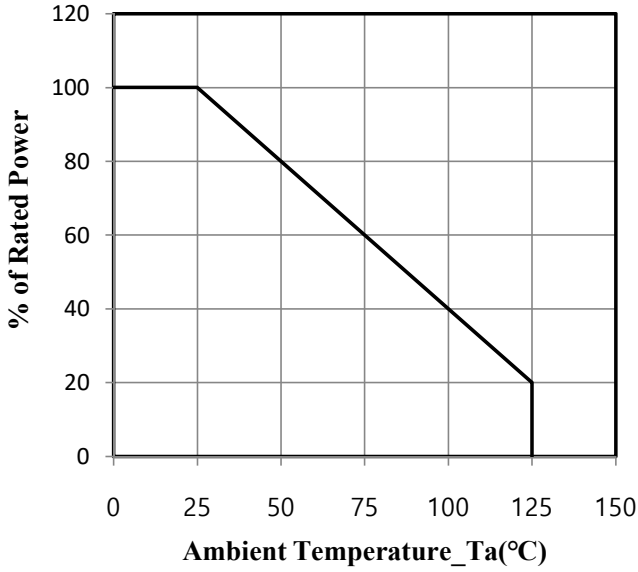
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20us)	Ppk	240	W
Peak Pulse Current (8/20us)	Ipp	16	A
ESD per IEC 61000-4-2 (Air)	V <sub>ESD</sub>	$\pm 17$	kV
ESD per IEC 61000-4-2 (Contact)		$\pm 20$	
Operating Junction Temperature Range	T <sub>J</sub>	-55 to +125	°C
Storage Temperature Range	T <sub>STG</sub>	-55 to +150	°C

### Electrical Characteristics (Ta= 25°C unless otherwise specified)

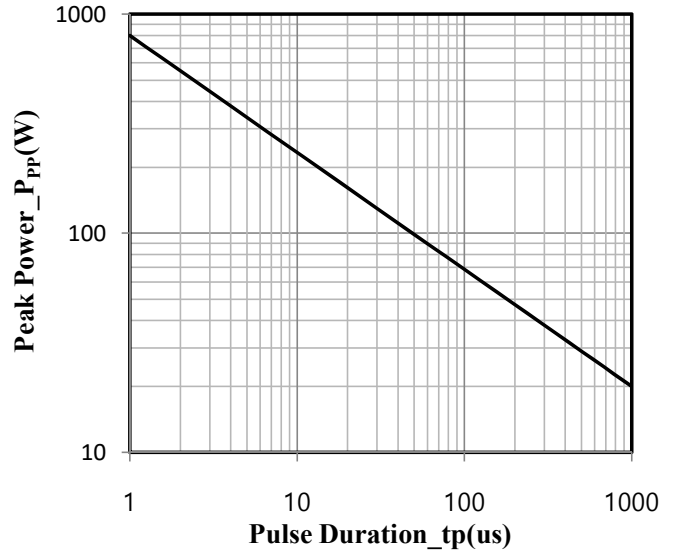
Characteristic	Symbol	Min.	Typ.	Max.	Unit	Test Condition
Reverse Working Voltage	V <sub>RWM</sub>	-	-	3.3	V	
Breakdown Voltage	V <sub>BR</sub>	3.5	-	-	V	I <sub>T</sub> = 2uA
Snap-Back Voltage	V <sub>SB</sub>	2.8	-	-	uA	I <sub>T</sub> = 50mA
Reverse Leakage Current	I <sub>R</sub>	-	-	1.0	uA	V <sub>RWM</sub> = 3.3V
Clamping Voltage	V <sub>C</sub>	-	-	6.5	V	I <sub>PP</sub> =1A(8×20us pulse)
		-	-	15	V	I <sub>PP</sub> =16A(8×20us pulse)
Junction Capacitance(Pin 1,2 to 3)	C <sub>J</sub>	-	-	25	pF	f=1MHz, V <sub>R</sub> =0V
Junction Capacitance(Pin 1 to 2)		-	-	18	pF	f=1MHz, V <sub>R</sub> =0V

**Ratings and Characteristics Curves (Ta=25°C unless otherwise noted)**

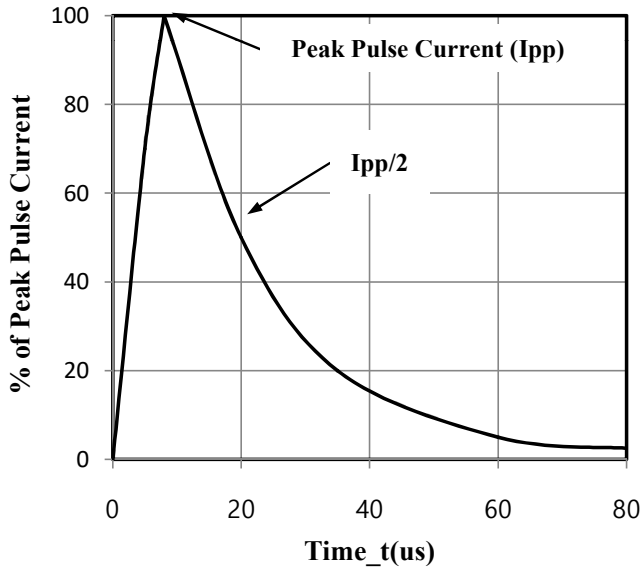
**Fig.1 Power Derating Curve**



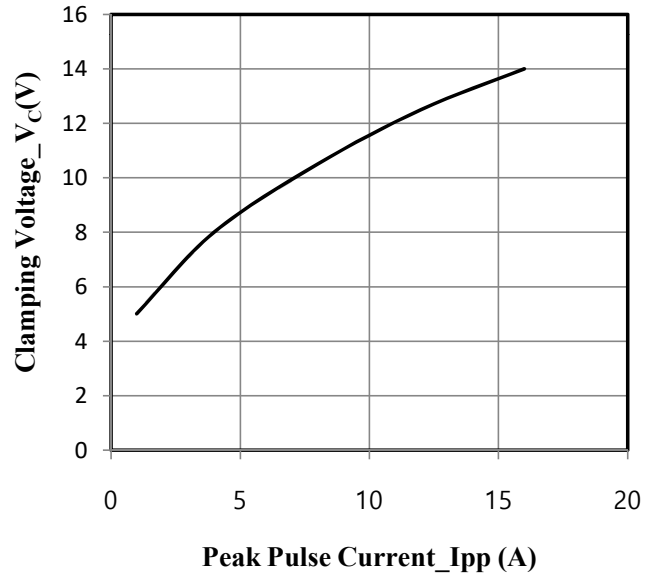
**Fig.2 Peak Pulse Power vs. Pulse Time**



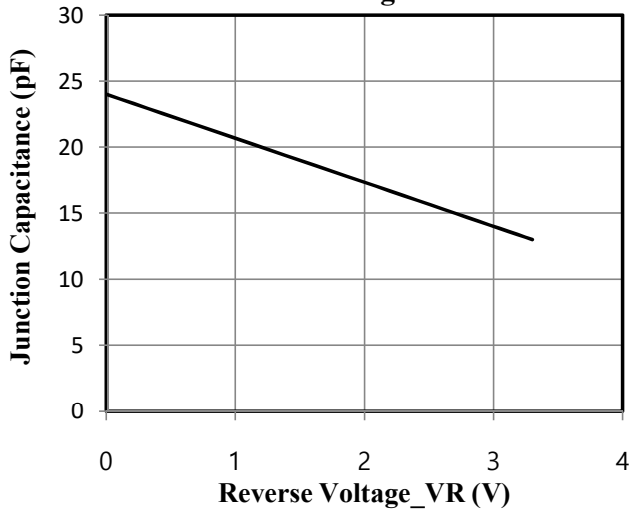
**Fig.3 8 × 20us Pulse Waveform**



**Fig.4 Clamping Voltage vs. Peak Pulse Current (tp=8/20us)**



**Fig.5 Junction Capacitance vs. Reverse Voltage**



**Fig. 6 ESD Clamping Voltage 8kV Contact per IEC61000-4-2**

